# PRODUCT BULLETIN Generic Copy

03 Jun 2008

SUBJECT: ON Semiconductor Product Bulletin #16123

TITLE: Data Sheet Update for 1N5400-series Rectifier Devices

PROPOSED FIRST SHIP DATE: 03 Jun 2008

AFFECTED PRODUCT DIVISION: Automotive & Power Regulation Group

#### FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor sales office or Mike Schager <mike.schager@onsemi.com>

#### **NOTIFICATION TYPE:**

ON Semiconductor considers this change approved. There is no change to form, fit, or function of the affected devices.

## **DESCRIPTION AND PURPOSE:**

ON Semiconductor has updated the 1N5400-series data sheet with the following changes.

Ifsm Rating Condition 8.3mS Single Half-Sine-Wave Ifsm Curve Tj = 25C

Operating Junction Temperature Range is changed to -65C to +150C

Hot Ir Condition and Limit are changed to 100C and 50 micro amps

Figures 3 & 4 Current Derating Temperature changed to 150C

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# **ON Semiconductor**



## **Product Bulletin #16123**

## AFFECTED DEVICE LIST

PART

1N5400

1N5400G

1N5400RL

1N5400RLG

1N5401

1N5401G

1N5401RL

1N5401RLG

1N5402

1110-102

1N5402G

1N5402RL

1N5402RLG

1N5404

1N5404G

1N5404RL

1N5404RLG

1N5406

1N5406G

1N5406RL

1N5406RLG

1N5407

1N5407G

1N5407RL

1N5407RLG

1N5408

1N5408G

1N5408RL

1N5408RLG

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